編號: 164

系所組別:生物醫學工程學系乙組

考試科目:電子學

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考試日期:0211,節次:1

※考生請注意:本試題不可使用計算機。請於答案卷(卡)作答,於本試題紙上作答者,不予計分。

- 1. A basic differential amplifier circuit is shown in Fig. 1. (a) Determine R_E and R_C such that $i_E = 80 \ \mu\text{A}$ and $v_{O1} = v_{O2} = -0.25 \ \text{V}$ when $v_1 = -1.0 \ \text{V}$, with $V_{BE}(\text{on}) = 0.7 \ \text{V}$ and neglecting the base currents. (b) Using the obtained R_E and R_C in part (a), determine v_{O1} and v_{O2} when $v_1 = -1.3 \ \text{V}$ and $v_1 = 0.7 \ \text{V}$, respectively. (20%)
- 2. Design an NMOS pass transistor logic circuit to perform the function Y = A + B (C + D). Assume that both variable and its complement are available as input signals. (10%)
- 3. An analog signal in the range 0 to 5V is to be converted to a digital signal using an A/D converter for a quantization error less than 1%. Please determine the required number of bits and the input voltage value that represents 1 LSB. (10%)
- 4. The op-amp in the circuit in Fig. 2 has an open-loop differential voltage gain of $A_d = 10^4$. Assume the op-amp is ideal one. Determine (a) the closed-loop voltage gain $A_o = V_o/V_s$, and (b) the resistances for R_{if} and R_{of} as shown in Fig. 2. (20%)
- 5. An equivalent high-frequency small-signal circuit of a MOSFET with a load resistance R_L is shown in Fig. 3. Give your derivation in detail for Miller capacitance, and cutoff frequency of this MOSFET. (20%)
- 6. The transistor parameters of the circuit as shown in Fig. 4 are $R_S = 2k\Omega$, $V_{TP} = -1.2V$, $k'_P = 40 \,\mu\text{A/V}^2$, and $\lambda = 0$. (a) Design the transistor width-to-length ratio such that $I_{DQ} = 1.5 \,\text{mA}$, and (b) find its small-signal voltage gain. (20%)

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Fig. 3





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